

*High Q R&D at FNAL:
a newly discovered surface treatment
to triple SRF cavity efficiency*

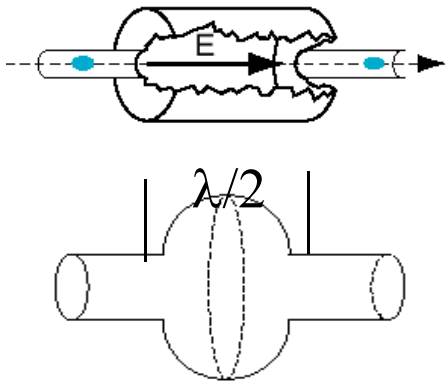
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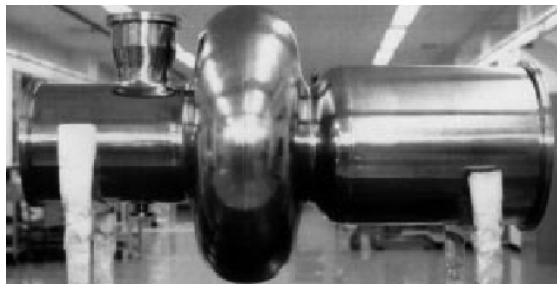
All Experimenters Meeting

Fermilab, July 22nd 2013

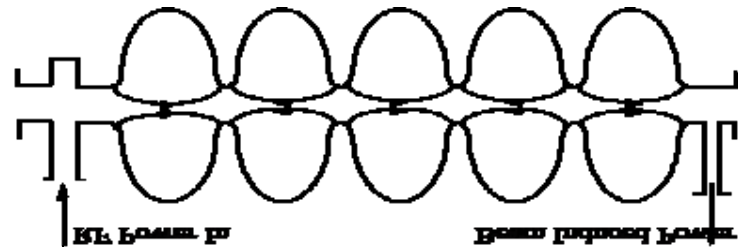
Superconducting RF cavities



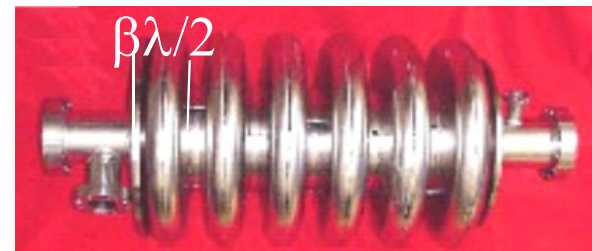
Basic Principle, $v/c = 1$



Single Cell



Multi-Cell Cavity



Squeezed Cells for $v/c = 0.5$

9

Q curve: past and present

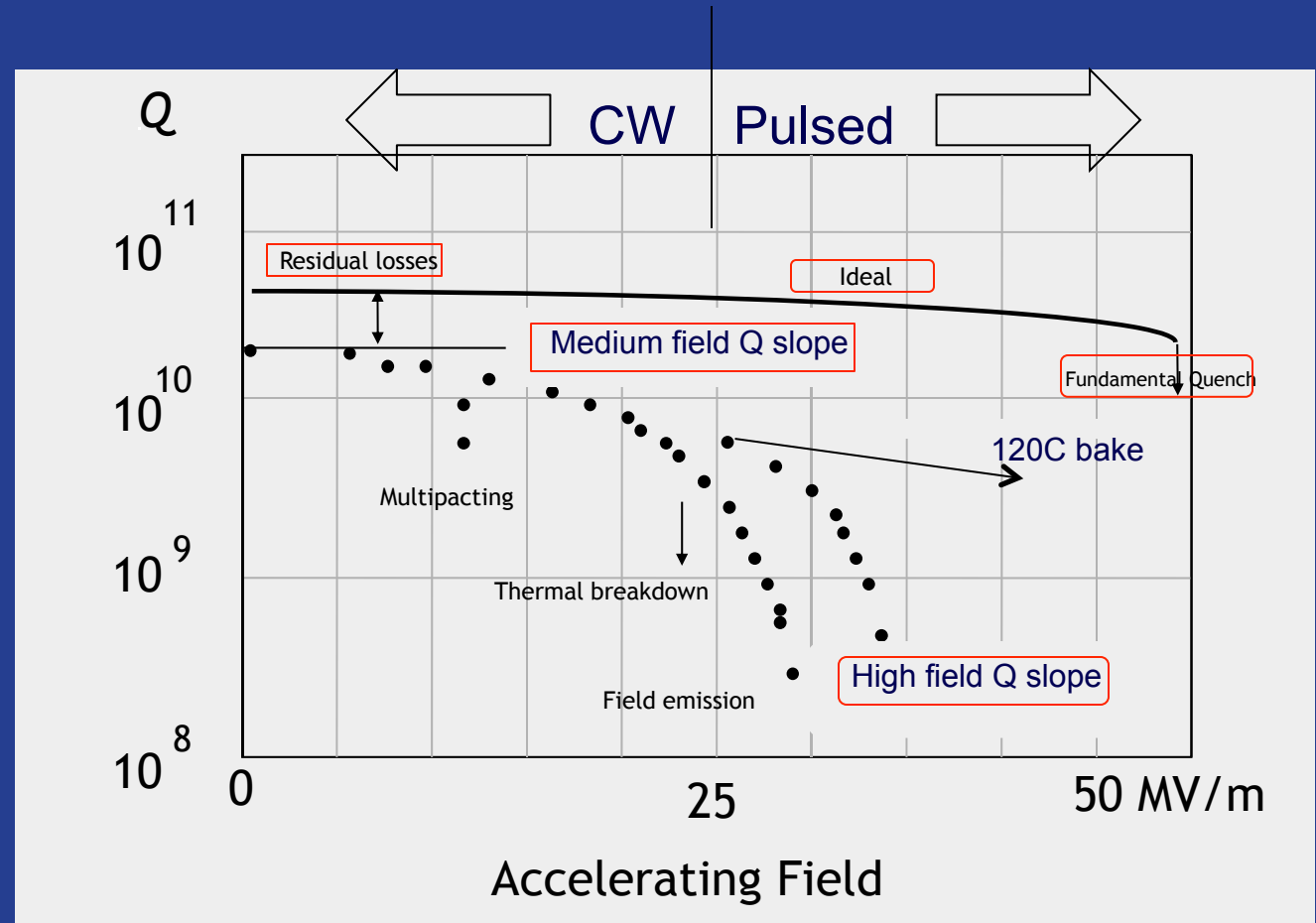
Among main factors of merit:

- Quality factor of the resonator
- Achievable gradients

$$Q_0 = \frac{\omega_0 \mu_0 \int_V |\mathbf{H}|^2 dv}{R_s \int_S |\mathbf{H}|^2 ds}$$

$$Q_0 = \frac{G}{R_s},$$

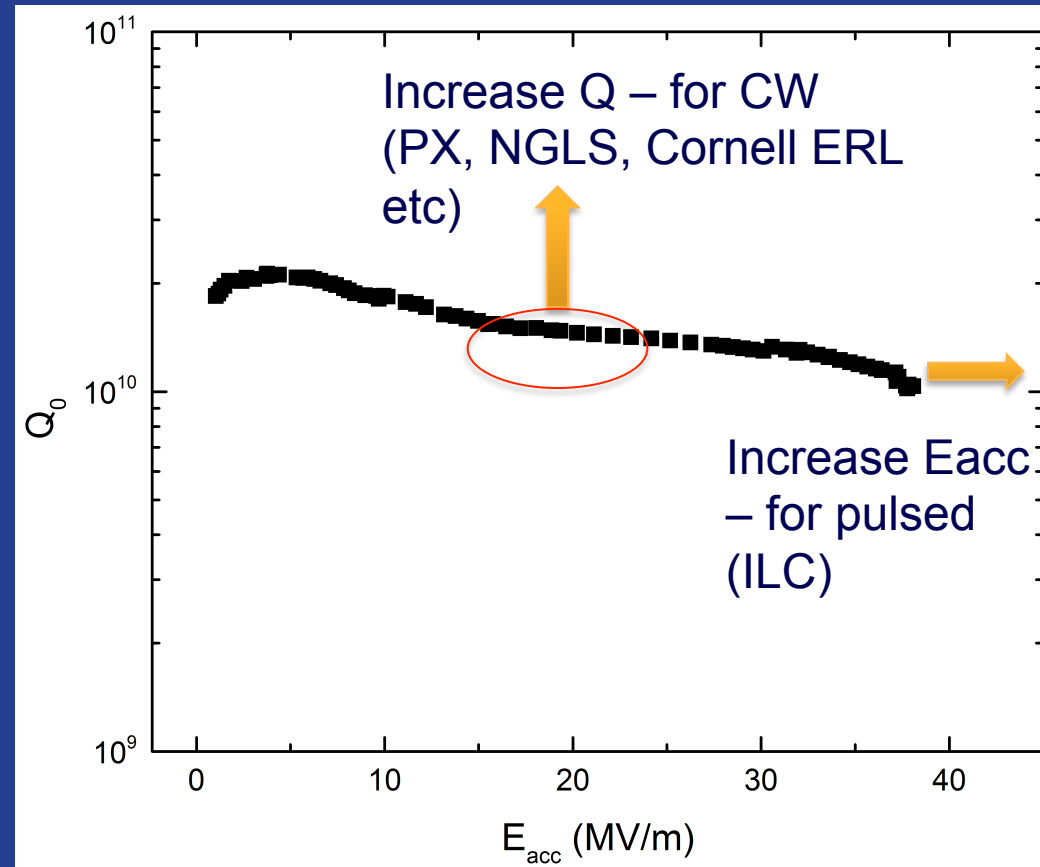
$$G = \frac{\omega_0 \mu_0 \int_V |\mathbf{H}|^2 dv}{\int_S |\mathbf{H}|^2 ds}$$



Steady progress due to basic understanding of limiting phenomena and invention of effective cures

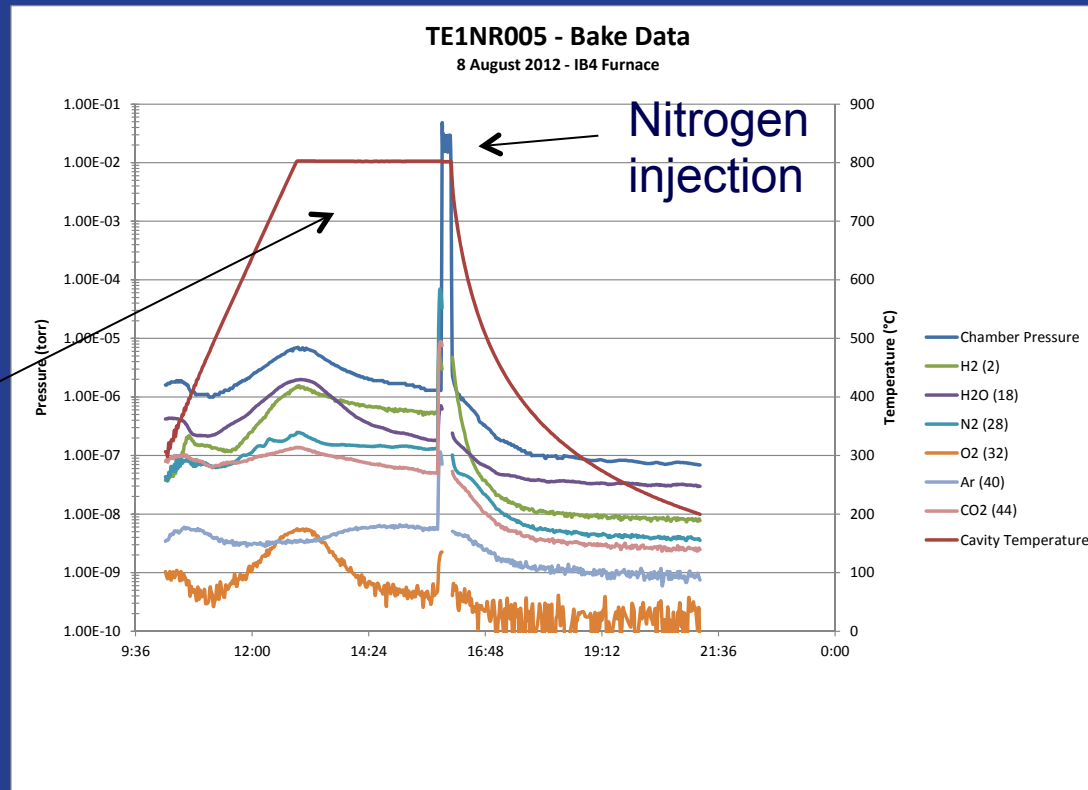
Need for higher Q

- Increasing Q of cavities
 - very important for high duty factor accelerators
 - virtually all planned superconducting machines (e.g. **Project X**, NGLS, ERLs, XFEL, ADS etc.)
- Capital and operational costs scale with dissipated power $\sim 1/Q$



New surface treatments for high Q: nitrogen doping

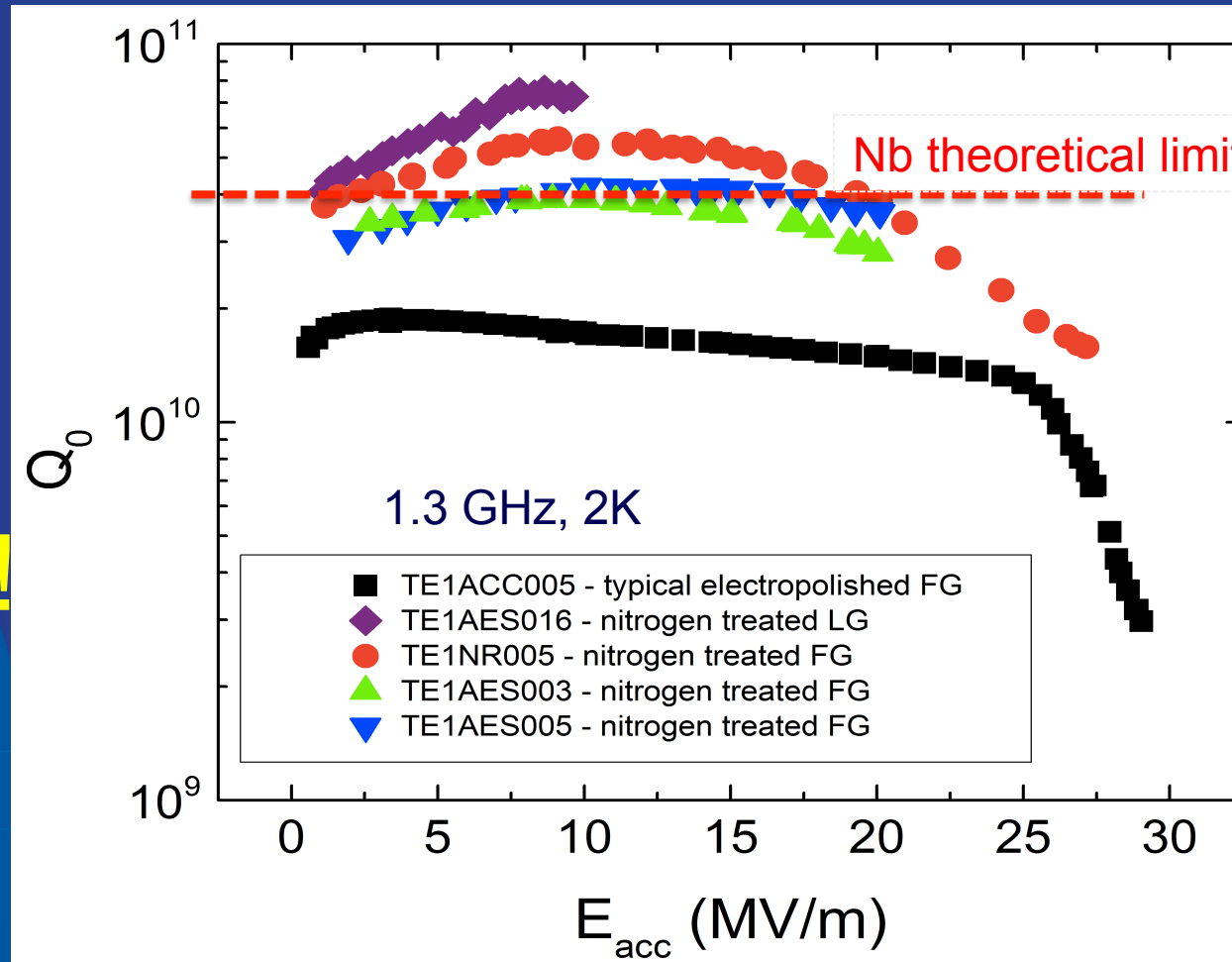
800C bake
in UHV



- 4 cavities treated in UHV high T furnace, with injection of small partial pressure of nitrogen
- T range 800-1000C for different duration, followed by different amount of material removal via electropolishing

All treated cavities doubled or tripled their efficiency:

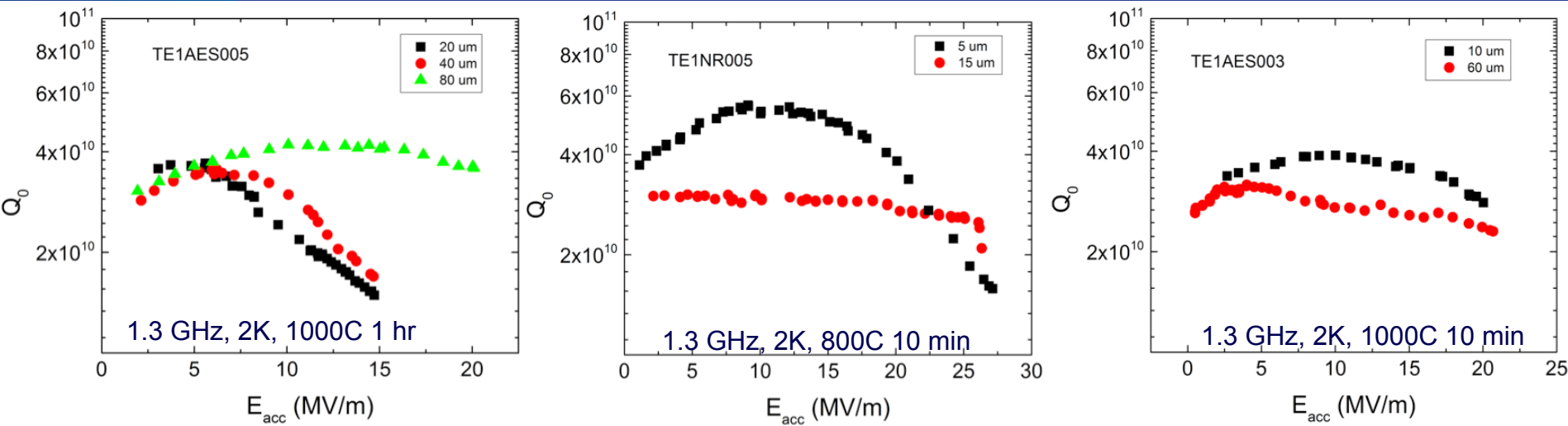
World
record
Q
values!



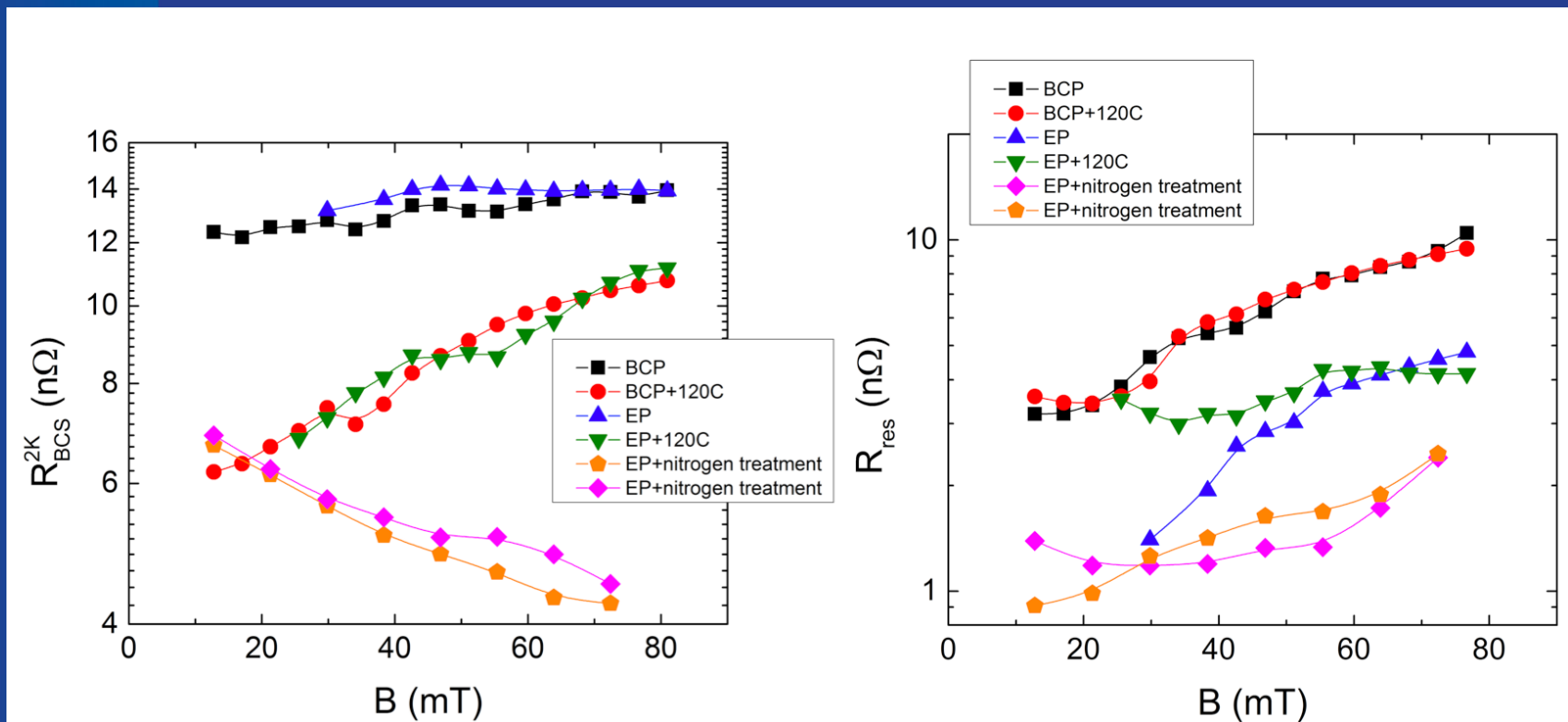
Anti Q-
slope!

Efficiency
gain up
to factor
of 3!

Q curves as a function of material removal via EP post-nitrogen treatment:



- Critical T measured for one cavity $\sim 9.2\text{K}$ (standard Nb)
- Studies as function of material removal post nitrogen treatment indicate ideal nitrogen to niobium concentration ratio which gives the anti-slope
- XPS and Auger studies ongoing to determine this ideal concentration

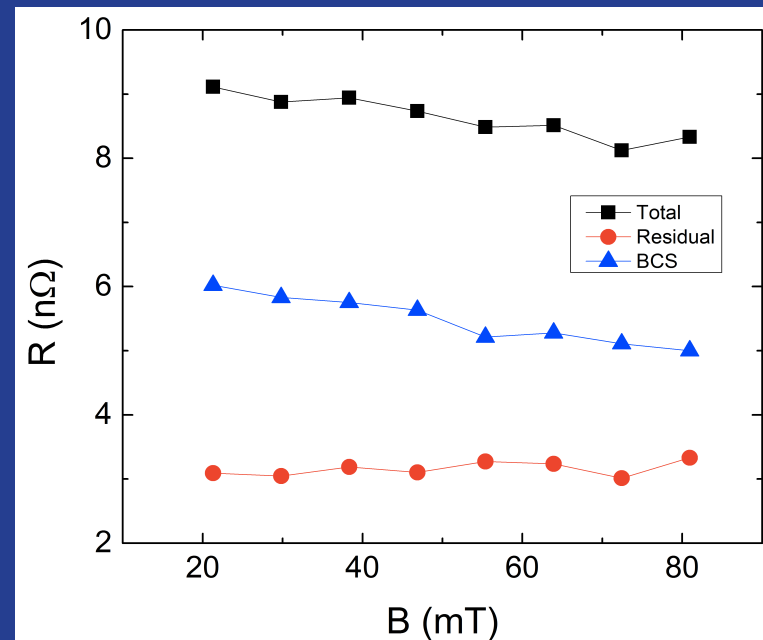
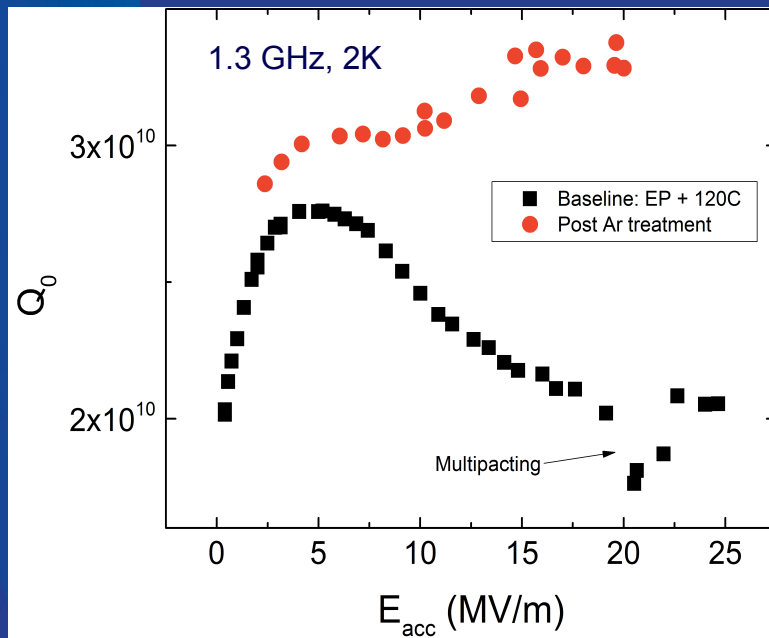


Deconvolution into the BCS and residual resistance reveals a decreasing with field T dependent component! Will try also on 3.9 GHz cavities

Doping with interstitial impurities: a solution for MFQS?

The cavity baked with argon

- Cavity baked at 800C for an hour in UHV, followed by an hour at 800C in partial pressure $\sim 2 \times 10^{-2}$ T of Argon $\rightarrow Q \sim 1 \times 10^7$
- Then ~ 7 micron removal via EP \rightarrow *again anti-Qslope!*
- **IMPLICATION: we have found the cure for the medium field Q-slope!**



Conclusions

- Just little over a year of high Q R&D has already produced breakthrough results
- The results represent a milestone for the SRF technology
- Results have triggered new R&D directions at other institutions, experimental and theoretical groups
- High Q R&D program ongoing exploring other ideas and optimizing the recipe found
- International High Q collaboration established (Cornell, DESY, Berkeley, Jlab, TRIUMF, HZB, KEK, IHEP...) with Fermilab playing a leading role